

DESCRIPTION

The MP44014 is a boundary conduction mode PFC controller that provides simple, high-performance, active power factor correction using minimal external components.

The output voltage is regulated accurately by a high-performance voltage mode amplifier with an accurate internal voltage reference.

The precise, adjustable output over-voltage protection greatly enhances system reliability.

The on-chip R/C filter on the current sense pin can potentially eliminate the external R/C filter.

The extremely low start-up current, quiescent current, and disable function reduces power consumption, resulting in excellent efficiency performance.

The MP44014 is available in a SOIC-8 package.

FEATURES

- Boundary Conduction Mode PFC Controller for Pre-Regulator
- Zero-Crossing Compensation to Minimum THD of the AC Input Current
- Precise Adjustable Output Over-Voltage Protection
- Ultra-Low (15 μ A) Start-Up Current
- Low Quiescent Current (0.46 μ A) at OVP Condition
- On-Chip Filter on Current Sense Pin
- Disable Function on ZCS Pin
- -750mA/+800mA Peak Gate Drive Current
- Available in SOIC-8 Packages

APPLICATIONS

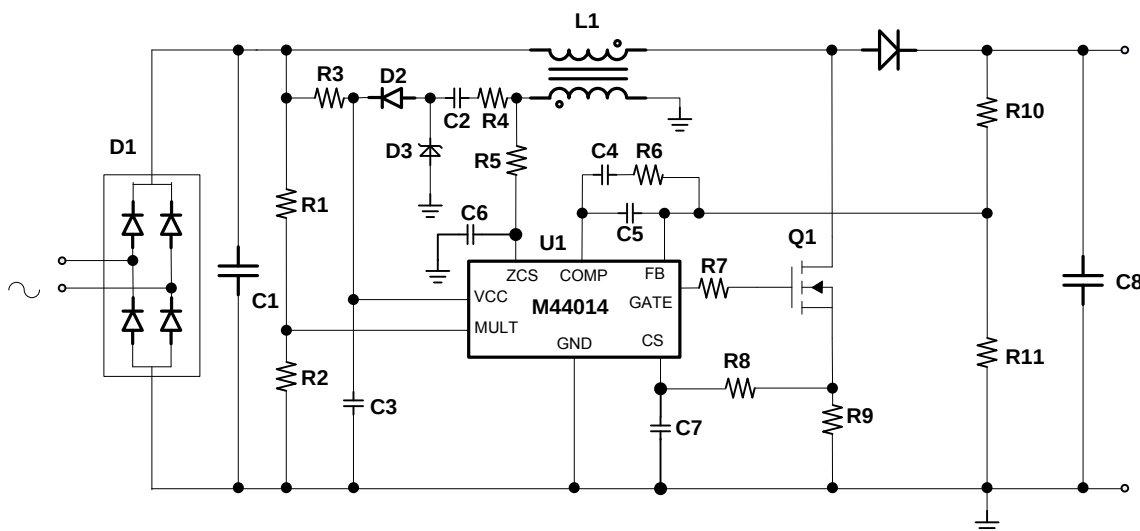
- Offline Adaptors
- Electronic Ballast
- LLC Front End
- Other PFC Pre-Regulators

All MPS parts are lead-free, halogen-free, and adhere to the RoHS directive. For MPS green status, please visit the MPS website under Quality Assurance.

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Other patents pending.

TYPICAL APPLICATION



ORDERING INFORMATION

Part Number	Package	Top Marking
MP44014GS*	SOIC-8	See Below

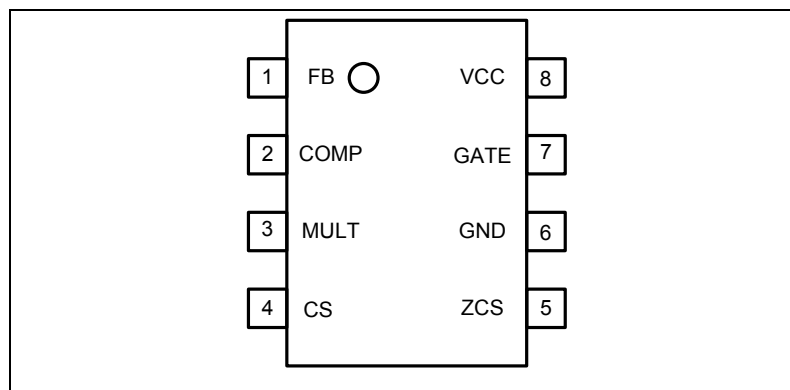
* For Tape & Reel, add suffix -Z (e.g. MP44014GS-Z)

TOP MARKING

MP44014
LLLLLLLL
MPSYWW

MP44014: Part number
 LLLLLLLL: Lot number
 MPS: MPS prefix
 Y: Year code
 WW: Week code

PACKAGE REFERENCE



ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

Supply voltage (VCC) -0.5V to self limit
 Analog inputs and outputs ⁽²⁾ -0.3V to 6.5V
 ZCS max. current -2.5mA to 10mA
 Continuous power dissipation (T_A = +25°C) ⁽³⁾
 SOIC-8 1.4W
 Junction temperature 150°C
 Lead temperature (solder) 260°C
 Storage temperature -55°C to +150°C

Recommended Operating Conditions ⁽⁴⁾

Supply voltage (VCC) 13.4V to 22V
 Analog inputs and outputs -0.3V to 6.5V
 Operating junction temp. (T_J)... -40°C to +125°C

Thermal Resistance ⁽⁵⁾ **θ_{JA}** **θ_{JC}**
 SOIC-8 90 45 ... °C/W

NOTES:

- Exceeding these ratings may damage the device.
- Except ZCS pin, which is self limited.
- The maximum allowable power dissipation is a function of the maximum junction temperature T_J(MAX), the junction-to-ambient thermal resistance θ_{JA}, and the ambient temperature T_A. The maximum allowable continuous power dissipation at any ambient temperature is calculated by D(MAX)=(T_J(MAX)-T_A)/θ_{JA}. Exceeding the maximum allowable power dissipation will produce an excessive die temperature, causing the regulator to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- The device is not guaranteed to function outside of its operating conditions.
- Measured on JESD51-7, 4-layer PCB.

ELECTRICAL CHARACTERISTICS

$V_{CC} = 15V$, $C_{GATE} = 1nF$, $T_J = -40^{\circ}C \sim +125^{\circ}C$, unless otherwise noted.

Parameter	Symbol	Condition	Min	Typ	Max	Units
Supply Voltage						
Operating range	V _{CC}	After turn on	10.7		21	V
Turn-on threshold	V _{CC_on}		11	12.3	13.8	V
Turn-off threshold	V _{CC_off}		8.7	9.8	10.8	V
Hysteresis	V _{CC_hys}		2.1		3	V
Zener voltage	V _Z	I _{IN} = 20mA	22	25	29	V
Supply Current						
Start-up current	I _{startup}	V _{CC} = 11V		15	30	μA
Quiescent current	I _q	No switch		2.5	3.2	mA
Operating current	I _{cc}	F _s = 70kHz, C _{LOAD} = 1nF		3.5	4.5	mA
Quiescent current	I _q	During OVP (either static or dynamic) or V _{FB} ≤ 150mV		0.46	0.7	mA
Multiplier						
Input bias current	I _{MULT}				-1	μA
Linear operation range	V _{MULT}		0		3	V
Output max. slope	ΔV _{CS} /ΔV _{MULT}	V _{MULT} = 0~0.6V V _{COMP} = upper clamp	1.60	1.90		V/V
Gain ⁽⁶⁾	K	V _{MULT} = 1V, V _{COMP} = 4V, T _J = 25°C	0.5	0.6	0.7	1/V
Error Amplifier						
Feedback voltage	V _{FB}	T _J = 25 °C	2.465	2.5	2.535	V
Feedback voltage line regulation	V _{FB_LR}	V _{CC} = 10.7V to 22V		2	5	mV
Feedback bias current	I _{FB}	V _{FB} = 2.6V			1	μA
Source current	I _{COMP_source}	V _{COMP} = 4V, V _{FB} = 2.4V, T _J = 25°C	-2.7	-4.7	-6.9	mA
Sink current	I _{COMP_sink}	V _{COMP} = 4V, V _{FB} = 2.6V, T _J = 25°C	3	5		mA
Upper clamp voltage	V _{COMP_H}	V _{FB} = 2V, I _{comp} = -0.5mA	5.5	6.1	6.5	V
Lower clamp voltage	V _{COMP_L}	V _{FB} = 2V, I _{comp} = -0.5mA	2.0	2.15	2.3	V
Current Sense Comparator						
Input bias current	I _{CS}	CS = 0			-1	μA
Turn-off delay	T _{DT}	MULT = 0.2V		190		ns
LEB time	T _{LEB}	MULT = 0.2V	45	70	95	ns
Current sense clamp voltage	V _{CS_Clamp}		1.6	1.72	1.83	V
Current sense offset	V _{CS_Offset}	V _{MULT} = 0V		26		mV
		V _{MULT} = 2.5V		8		mV
Zero Current Sensor						
Upper clamp voltage	V _{ZCSclamp_H}	I _{ZCS} = 2.5mA	7.1	7.8	8.6	V

ELECTRICAL CHARACTERISTICS (continued)

$V_{CC} = 15V$, $C_{GATE} = 1nF$, $T_J = -40^{\circ}C \sim +125^{\circ}C$, unless otherwise noted.

Parameter	Symbol	Condition	Min	Typ	Max	Units
Lower clamp voltage	$V_{ZCS_{clamp_L}}$	$I_{ZCS} = -2.5mA$	0.2	0.5	0.7	V
Zero current sensing threshold	V_{ZCS_H}	V_{ZCS} rising		2.1	2.21	V
	V_{ZCS_L}	V_{ZCS} falling	1.45	1.56	1.66	V
ZCS_DISABLE threshold	$V_{ZCS_DISABLE_}$		140	185	230	mV
ZCS_EN threshold	V_{ZCS_EN}		260	320	380	mV
Source current capability	I_{ZCS_source}		-1.8			mA
Restart current after disable	I_{ZCS_res}		55	85		μA
Re-Starter						
Re-start time	T_{start}		80	175	280	μs
Over Voltage						
Dynamic OVP current	I_{OVP}		35	40	45	μA
Hysteresis	I_{OVP_Hys}			30		μA
Static OVP threshold	V_{OVP}		2.15	2.25	2.35	V
Gate Driver						
Dropout voltage	V_{OH}	$I_{GDsource} = 20mA$		2.4	3.1	V
		$I_{GDsource} = 200mA$		3.9	5.0	V
	V_{OL}	$I_{GDsink} = 200mA$		0.9	1.9	V
Voltage fall time	T_f			30	70	ns
Voltage rise time	T_r			40	80	ns
Max. output drive voltage	V_{D_max}		12	13.5	15.5	V
Source current capability	I_{Gate_source}			-750		mA
Sink current capability	I_{Gate_sink}			800		mA
UVLO saturation voltage	$V_{Saturation}$	$V_{CC} = 0$ to V_{CC_ON} , $I_{Gate_sink} = 10mA$			0.3	V

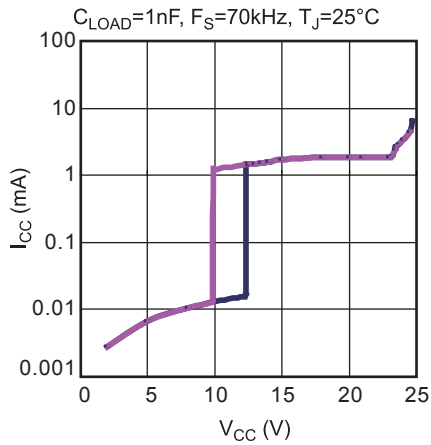
NOTES:

6) The multiplier output is given by: $V_{cs} = K \cdot V_{MUTL} \cdot (V_{COMP} - 2.5)$.

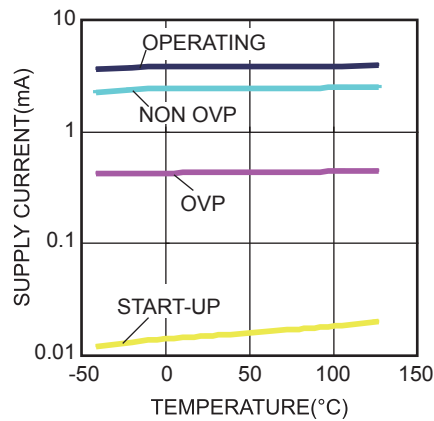
7) Guaranteed by design.

TYPICAL PERFORMANCE CHARACTERISTICS

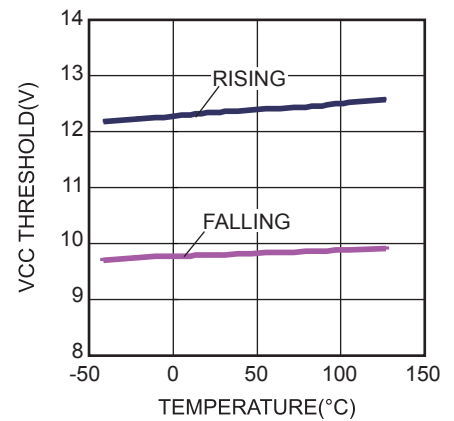
Supply Current vs. Supply Voltage



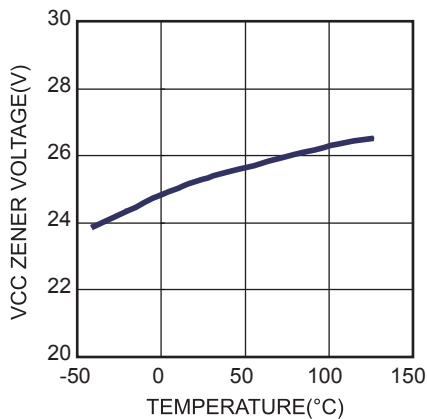
Supply Current vs. T_J



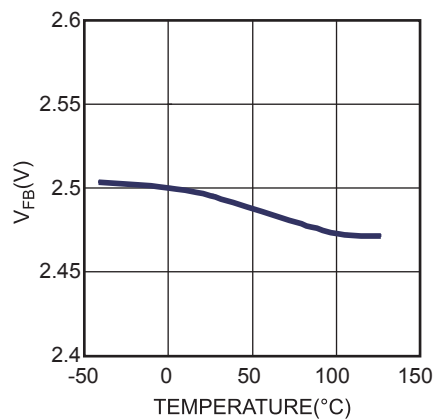
Start-Up & UVLO vs. T_J



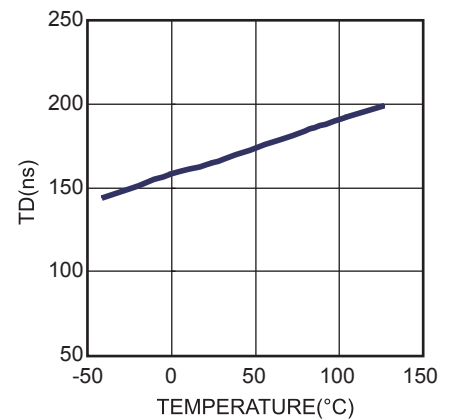
VCC Zener Voltage vs. T_J



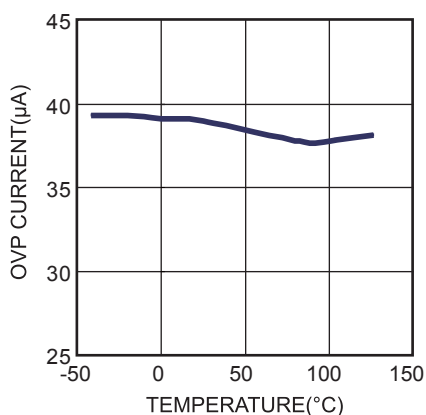
Feedback Reference vs. T_J



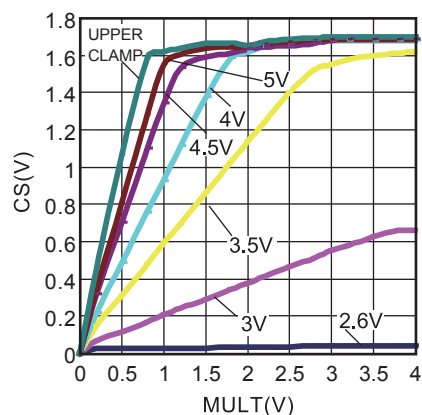
Delay-to-Output vs. T_J



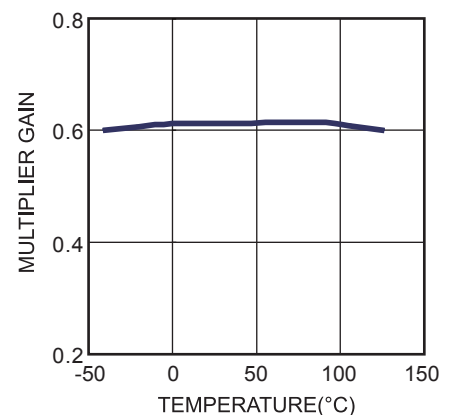
OVP Current vs. T_J



Multiplier Characteristic

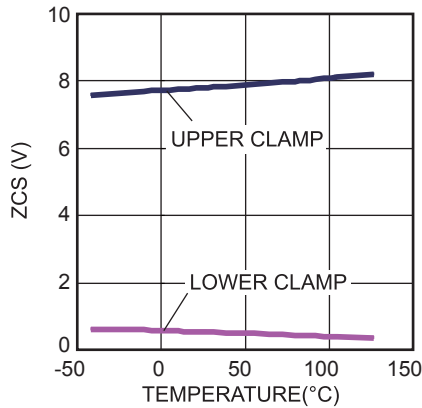


Multiplier Gain vs. T_J

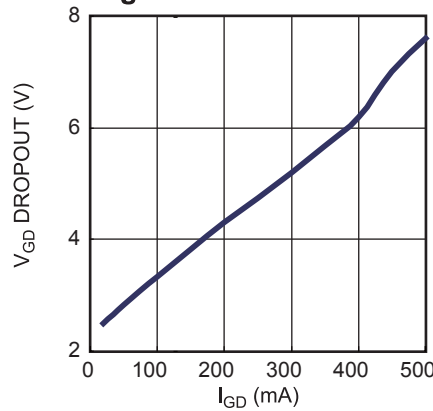


TYPICAL PERFORMANCE CHARACTERISTICS (*continued*)

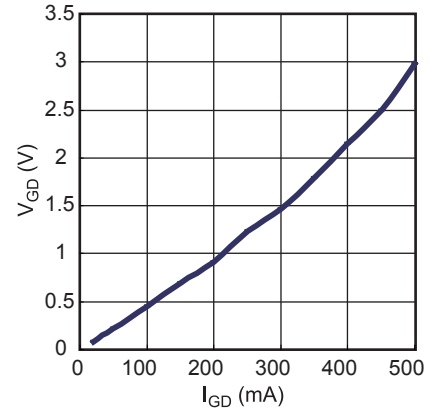
ZCS Clamp Levels vs. T_J



Gate-Drive Output
High Saturation



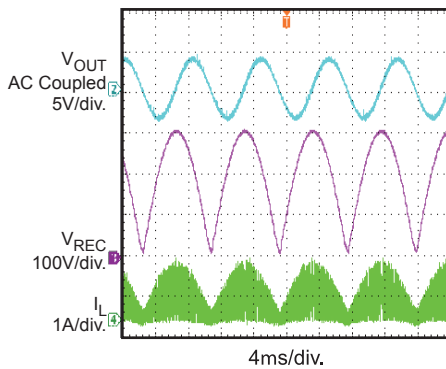
Gate-Drive Output
Low Saturation



TYPICAL PERFORMANCE CHARACTERISTICS (*continued*)

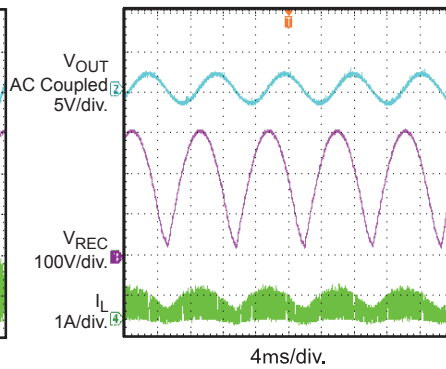
Steady State

$P_{OUT} = 100W$



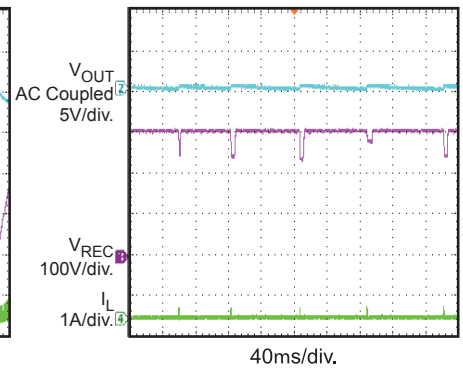
Steady State

$P_{OUT} = 50W$

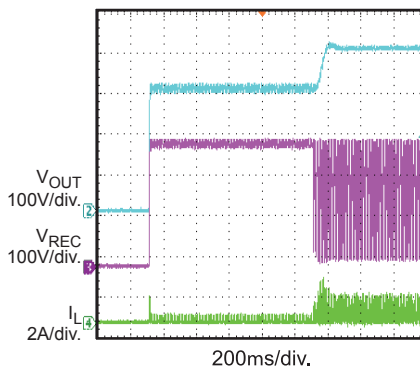


Steady State

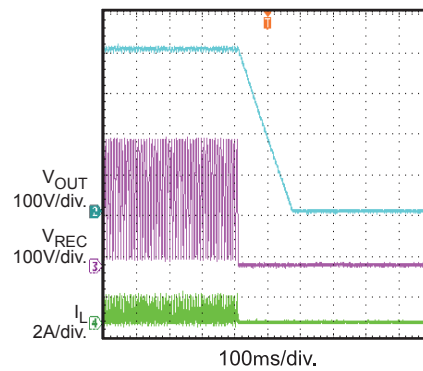
$P_{OUT} = 0W$



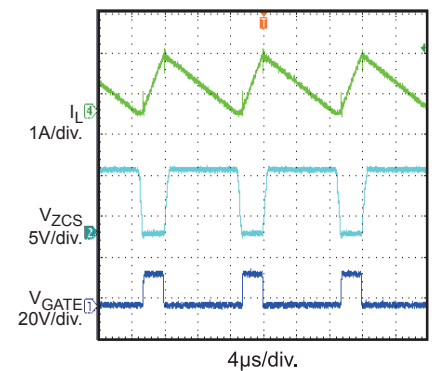
Start-Up



Shutdown

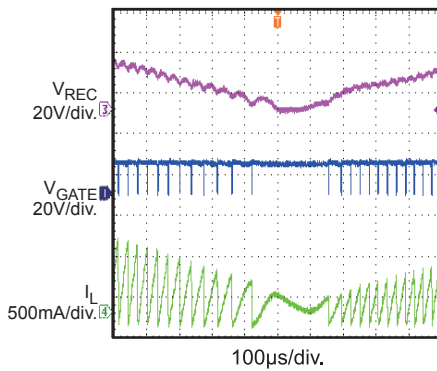


Zero-Current Sensing

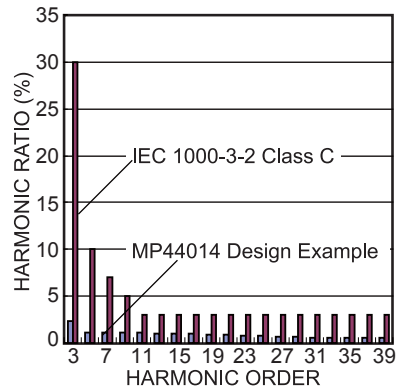


Zero-Crossing Compensation

$V_{AC} = 85V$



Harmonics



PIN FUNCTIONS

Pin #	Name	Description
1	FB	Feedback. The output voltage is fed into FB through a resistor divider.
2	COMP	Output of the error amplifier. A compensation network is connected between COMP and FB.
3	MULT	Input of the multiplier. Connect MULT to the rectified main voltage via a resistor divider to provide the sinusoidal reference for the current control loop.
4	CS	Current sense. The current through the MOSFET is fed into CS via a resistor. The resulting voltage on CS is compared with the output of the internal multiplier to get an internal sinusoidal-shaped reference to determine the MOSFET's turn-off. The on-chip R/C filter can reduce high frequency noise on CS. Also, suggest to add a RC filter on the CS pin in case of switching noise is too large.
5	ZCS	Inductor's zero-crossing current sensing input. A negative transition edge triggers the MOSFET's turn-on. Suggest to connect a 22pF cap from this ZCS to GND to tune ZVS point.
6	GND	Ground.
7	GATE	Gate driver output. The high output current of the gate driver is able to drive a low-cost power MOSFET. The high-level voltage of GATE is clamped to 12V in case GATE is supplied with a high VCC.
8	VCC	Supply voltage for both the signal path of the IC and the gate driver. A bypass capacitor from VCC to ground is needed to reduce noise.

FUNCTIONAL BLOCK DIAGRAM

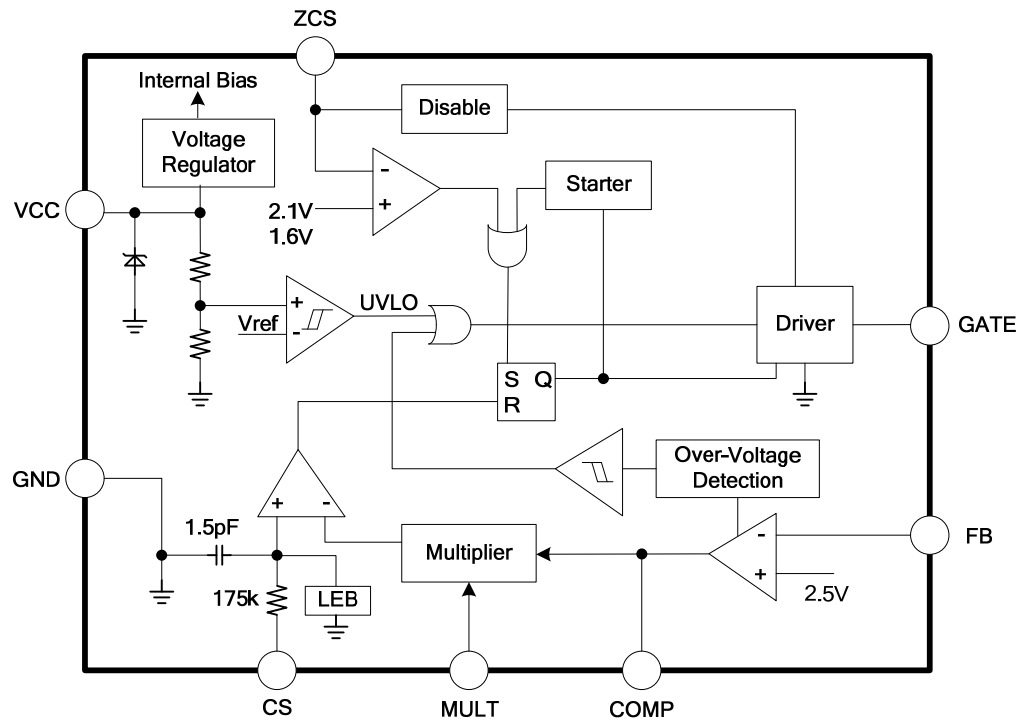


Figure 1: Functional Block Diagram

Boundary Conduction Mode

When the current of the boost inductor reaches zero, the voltage on the inductor is reversed. ZCS then generates the turn-on signal of the MOSFET by sensing the falling edge of the voltage on the auxiliary winding coupled with the inductor. If the ZCS voltage rises above 2.1V, the comparator waits until the voltage falls below 1.6V. Once the voltage falls below 1.6V, the MP44014 turns on the MOSFET. The 7.8V high clamp and 0.55V low clamp protect ZCS. The internal 175 μ s timer generates a signal to turn on the MOSFET if the driver signal has been low for more than 175 μ s. This also allows the MOSFET to turn on during the start-up period since no signal is generated from ZCD during start-up.

Zero-Crossing Compensation

The MP44014 offers 30mV voltage offset for the multiplier output near the zero crossing of the line voltage (which can force the circuit to process more energy at the bottom of the line voltage). With this function, the THD of the current is reduced.

To prevent redundant energy, this offset is reduced as the instantaneous line voltage increases. Therefore the offset will be negligible near the top of the line voltage.

Power Factor Correction

The MP44014 senses the inductor current through the current sense pin and compares it

to the sinusoidal-shaped signal, which is generated from the output of the multiplier. When the external power MOSFET turns on, the inductor current rises linearly. When the peak current hits the sinusoidal-shaped signal, the external power MOSFET begins to turn off, and the diode turns on. Also, the inductor current begins to fall. When the inductor current reaches zero, the power MOSFET begins to turn on again, which causes the inductor current to start rising again. The power circuit works in boundary conduction mode, and the envelope of the inductor current is sinusoidal shaped. The average input current is half of the peak current, so the average input current is also sinusoidal shaped. A high power factor can be achieved through this control method (see Figure 4).

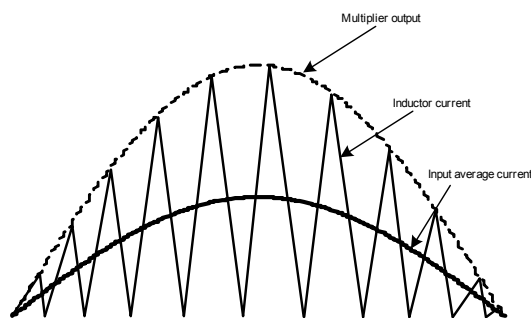


Figure 4: Inductor Current Waveform

The control flow chart of the MP44014 is shown in Figure 5.

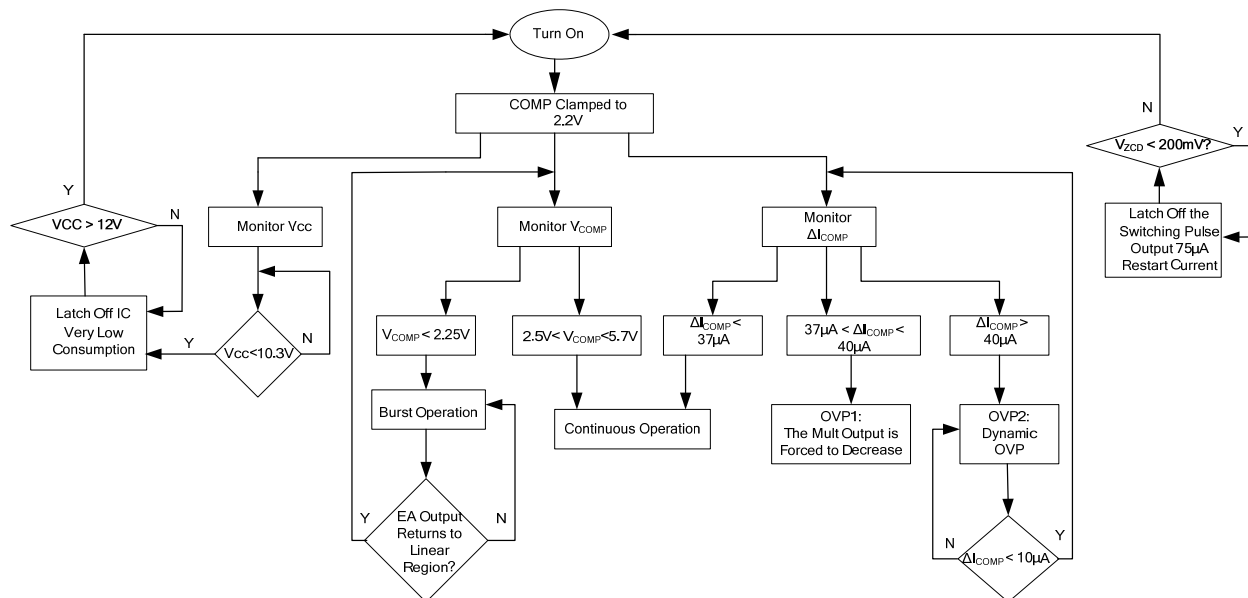
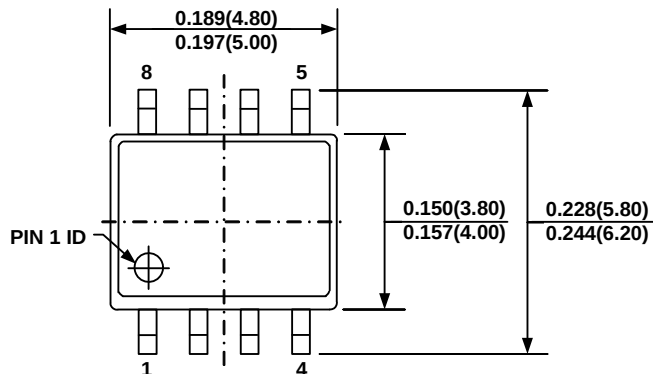


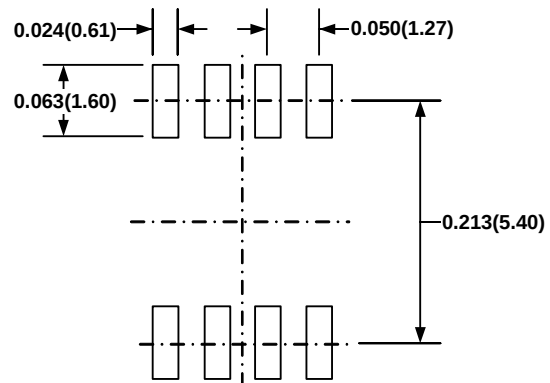
Figure 5: Control Flow Chart

PACKAGE INFORMATION

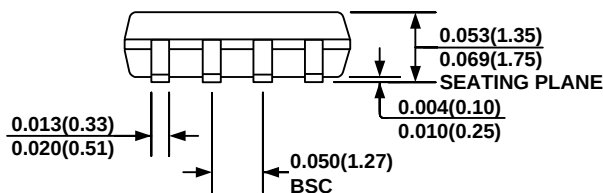
SOIC-8



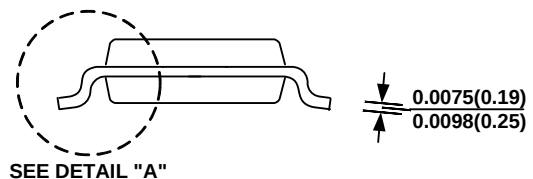
TOP VIEW



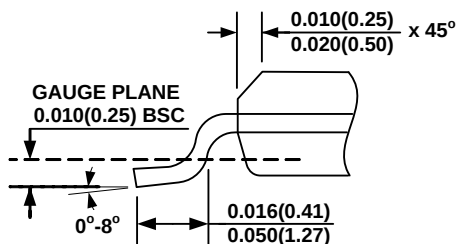
RECOMMENDED LAND PATTERN



FRONT VIEW



SIDE VIEW



DETAIL "A"

NOTE:

- 1) CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
- 2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- 3) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
- 4) LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
- 5) DRAWING CONFORMS TO JEDEC MS-012, VARIATION AA.
- 6) DRAWING IS NOT TO SCALE.

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